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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

**EBINA** 

Serial No.: 10/050,793

Filing Date: January 18, 2002

For: SEMICONDUCTOR DEVICES

AND METHODS FOR

MANUFACTURING THE SAME

Examiner: T. L. Dickey

Art Unit: 2826

## TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sirs:

In accordance with 37 CFR §§ 1.56, 1.97, and 1.98, enclosed please find Form PTO-1449 listing the attached references which might be deemed material to the examination of the above-identified application.

## A. <u>Non-English Language References</u>

Enclosed is a search report for a counterpart application. The search report
Examiner has provided comments on the relevancy of any non-English language
references cited in the search report.

- The specification incorporates comments on the relevancy of Non-English language references.
- Set forth below are comments provided by the applicant's home country counsel on the relevancy of non-English language references:
- The Notice of Reasons of Rejection for Japanese Patent Application 2001-011858 (from which priority is claimed in U.S. Serial No. 10/050,792), cites JP05-041488 and JP05-218316, which were previously cited in an IDS. The Notice of Reasons of Rejection for Japanese Patent Application 2000-382395 (from which priority is claimed in U.S. Serial No. 10/014,612), cites JP05-041488 and JP05-218316, which were previously cited in an IDS. An English language abstract has been submitted for JP62-128561.

Page 1 of 3

В.		The information disclosure statement submitted herewith is being filed									
	1)	within three months of the filing date of a national application other than a									
		continued prosecution application under 1.53(d);									
	2)	within three months of the date of entry into the national stage as set forth in									
		1.491 in an international application;									
	3)	before the mailing date of a first Office Action on the merits;									
	4)	before the mailing date of a first Office Action after filing of a Request for									
		Continued Examination under 1.114; or									
	5)	before the mailing date of a first Office Action after filing of a Continued									
		Prosecution Application.									
C.		The information disclosure statement transmitted herewith is being filed after the									
		period specified in paragraph B, but before the mailing date of a final action under									
		1.113, a Notice of Allowance under 1.311, or an action otherwise closing									
		prosecution, and is accompanied by:									
	1)	a Statement under 1.97(e); <u>or</u>									
	2)	a fee of \$180 as set forth in 1.17(p).									
D.		The information disclosure statement transmitted herewith is being filed after the									
		period specified in paragraph C, but before payment of the issue fee, and is									
		accompanied by:									
	1)	a Statement under 1.97(e); <u>and</u>									
	2)	a fee of \$180 as set forth in 1.17(p).									
		STATEMENT UNDER 1.97(e)									
	I, the	person signing below, certify									
		that each item of information contained in the information disclosure statement									
		was first cited in any communication from a foreign patent office in a counterpart									
		foreign application not more than three months prior to the filing of the statement.									
		37 C.F.R. 1.97(e)(1).									

- that no item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of information contained in the information disclosure statement was known to any individual designated in 1.56(c) more than three months prior to the filing of the statement. 37 C.F.R. 1.97(e)(2).
- Please charge any insufficiency or credit any overpayment to Deposit Account No. 50-0585. A duplicate of this letter is enclosed for fee processing.

Respectfully submitted,

Han 5 Kay

Alan S. Raynes

October 16 2003

Date

Reg. No. 39,809

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## Certificate of Mailing

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail on Oct. \_\_\_\_\_\_, 2003 and is addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Alan S. Ravnes

Oct. 16, 2003

(Date)

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		6	2	4	6	1	0	4	12Jun01	Tsuda et al.					
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		Notice of Reasons of Rejection for Japanese Patent Application No. 2001-011858 (from which priority is claimed in U.S. Serial No. 10/050,792), which cites JP05-041488 and JP05-218316, which were previously cited in an IDS.													
		Notice of Reasons of Rejection for Japanese Patent Application No. 2000-382395 (from which priority is claimed in U.S. Serial No. 10/014,612), which cites JP05-041488 and JP05-218316, which were previously cited in an IDS.													
	Parke et al., "Bipolar-FET Hybrid-Mode Operation of Quarter-Micrometer SOI MOSFET's," IEEE Electron Device Letters, Vol. 14, No. 5, May 1993, pp. 234-236.										е				
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* EXAMINEF	R: Initia	il if references form with r	e consi	dered mmuni	, whet	her or to ap	not ci plican	tation is	in conformance	e with MPEP 609; I	Draw line through citation	on if not in c	onformance	and not consider	ed.